

TOSHIBA RF POWER AMPLIFIER MODULE

# S-AV38

RF POWER AMPLIFIER MODULE for VHF BAND

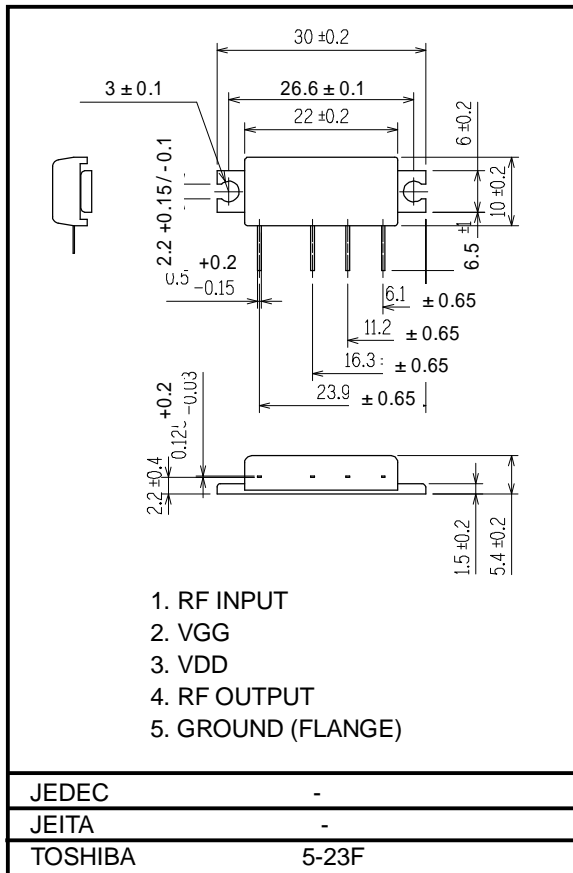
· for digital use

**MAXIMUM RATINGS (Tc = 25 )**

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V <sub>DD</sub>	17	V
DC Supply Voltage	V <sub>GG</sub>	7	V
Input Power	P <sub>i</sub>	17	dBmW
Operating Case Temperature Range	T <sub>c (opr)</sub>	-30~100	
Storage Temperature Range	T <sub>stg</sub>	-40~110	

**PACKAGE OUTLINE**

Unit in mm



Weight: 3.5g

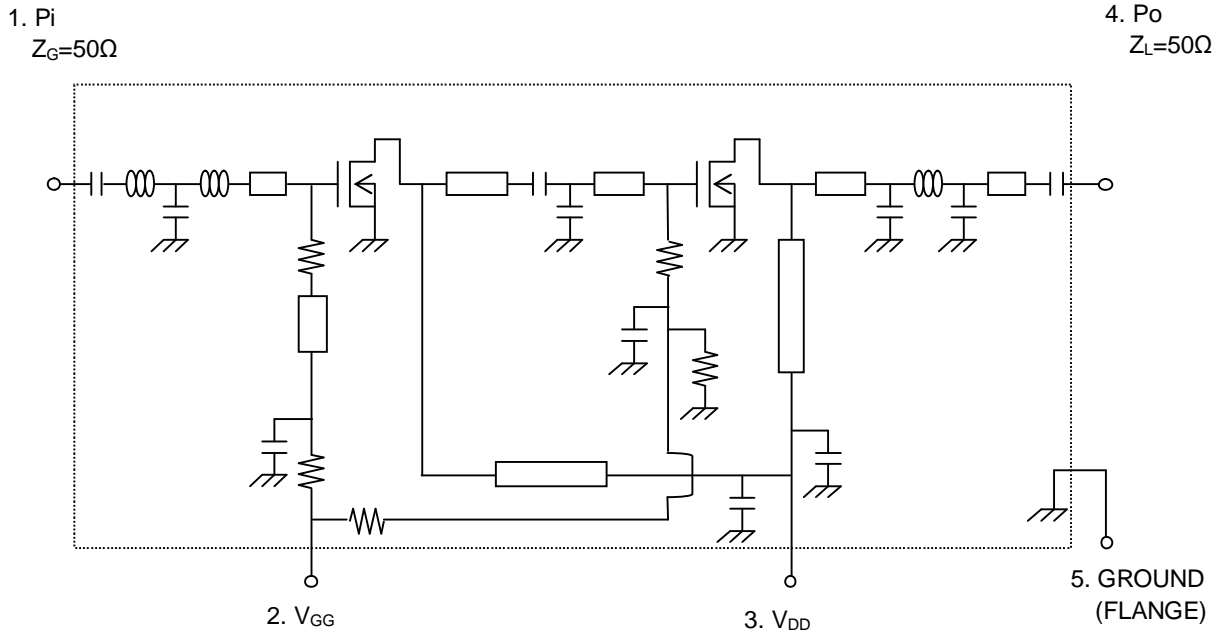
## ELECTRICAL CHARACTERISTICS (T<sub>c</sub> = 25 , Z<sub>G</sub> = 50 )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Frequency Range	f <sub>range</sub>	—	260	—	266	MHz
Output Power	P <sub>o</sub>	V <sub>DD</sub> = 7.2V, P <sub>o</sub> =35dBmW(P <sub>i</sub> =adjust) I <sub>DD</sub> =1.7A(V <sub>GG</sub> = adjust) , Z <sub>L</sub> = 50 After that P <sub>i</sub> = 15dBmW	38.8	—	—	dBmW
Input Power	P <sub>i</sub>	V <sub>DD</sub> = 7.2V, I <sub>DD</sub> = 1.7A (V <sub>GG</sub> = adjust) P <sub>o</sub> = 35dBmW(P <sub>i</sub> =adjust), Z <sub>L</sub> = 50	—	—	5	dBmW
Gate Bias Voltage	V <sub>GG</sub>	V <sub>DD</sub> = 7.2V, I <sub>DD</sub> = 1.7A (V <sub>GG</sub> = adjust) P <sub>o</sub> = 35dBmW(P <sub>i</sub> =adjust), Z <sub>L</sub> = 50	2.5	—	3.5	V
Gate Bias Current	I <sub>GGBias</sub>	V <sub>DD</sub> = 7.2V, I <sub>DD</sub> = 1.7A (V <sub>GG</sub> = adjust) P <sub>o</sub> = 35dBmW (P <sub>i</sub> = adjust), Z <sub>L</sub> = 50 After that P <sub>i</sub> OFF	—	—	1	mA
Adjacent-Channel Power Ratio	ACP	V <sub>DD</sub> = 7.2V, I <sub>DD</sub> = 1.7A (V <sub>GG</sub> = adjust) P <sub>o</sub> = 35dBmW (P <sub>i</sub> = adjust), Z <sub>L</sub> = 50 Modulated Wave : /4-DQPSK (α=0.5, 32kbps) Band Width : 16kHz Frequency Offset : 25kHz	—	—	-35	dB
Second Harmonic	2nd HRM	V <sub>DD</sub> = 7.2V, I <sub>DD</sub> = 1.7A (V <sub>GG</sub> = adjust) P <sub>o</sub> = 35dBmW (P <sub>i</sub> = adjust), Z <sub>L</sub> = 50	—	—	-27	dB
Third Harmonic	3rd HRM		—	—	-30	dB
Harmonic	HRM		—	—	-35	dB
Rate of Adjustment for Input Load	VSWR <sub>in</sub>	Input VSWR ( When RF output pin connects 50 Load )	—	—	3	—
Rate of Adjustment for Output Load	VSWR <sub>out</sub>	Input VSWR ( When RF input pin connects 50 Load )	—	—	2.5	—
Relative Phase Variation	—	V <sub>DD</sub> = 7.2V, I <sub>DD</sub> = 1.7A (V <sub>GG</sub> = adjust) P <sub>o</sub> = 5 to 35dBmW (P <sub>i</sub> = adjust) Z <sub>L</sub> = 50 (@ P <sub>o</sub> = 35dBmW)	—	—	± 12	°
Load Mismatch	—	V <sub>DD</sub> = 7.2V, I <sub>DD</sub> = 1.7A (V <sub>GG</sub> = adjust) P <sub>o</sub> = 35dBmW (P <sub>i</sub> = adjust, Z <sub>L</sub> = 50 ) VSWR LOAD 20: 1 ALL PHASE	No Degradation			—
Stability	—	V <sub>DD</sub> = 6.0 to 9.0V, V <sub>GG</sub> = 1 to 5V P <sub>i</sub> = -40 to 13 dBmW VSWR LOAD 3: 1 ALL PHASE	All spurious output than 60dB below desired signal			—

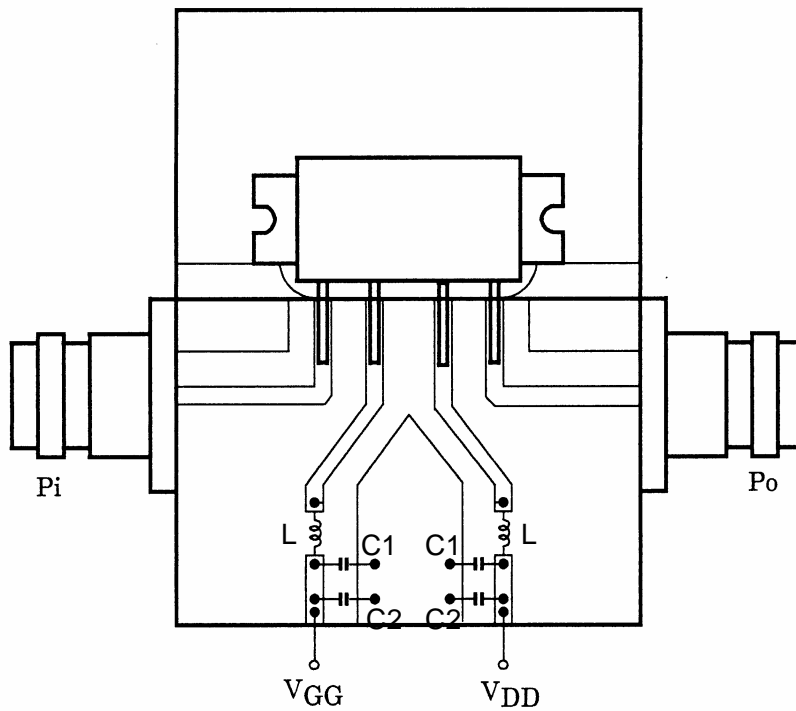
### Caution

- This product has intersetting cap. Please pay attention for exceeding stress and foreign matter in your application. And not to take away the cap.
- Do not break, cut, crush or dissolve chemically. Dispose of this product properly according to law. Do not intermingle with normal industrial or domestic waste.
- This product is electrostatic sensitivity, please handle with caution.

**SCHEMATIC**



**TEST FIXTURE**



- C1 : 10000pF
- C2 : 10 μF
- L : 0.8 ENAMEL WIRE 8T 5ID

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